DISCRETE SEMICONDUCTORS



Product specification Supersedes data of November 1993 File under Discrete Semiconductors, SC01 1996 Apr 17



FEATURES

- Small plastic SMD package
- Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 200 V
- Repetitive peak reverse voltage: max. 250 V
- Repetitive peak forward current: max. 625 mA
- Forward voltage: max. 1 V.

APPLICATIONS

• General purpose where high breakdown voltages are required.

DESCRIPTION

The BAV23S consists of two general purpose diodes connected in series fabricated in planar technology, and encapsulated in the small plastic SMD SOT23 package.

2

3

PINNING		
PIN	DESCRIPTION	
1	anode	
2	cathode	
3	common	

3

MAM232

connection



Fig.1 Simplified outline (SOT23) and symbol.

1

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode	Per diode				
V _{RRM}	repetitive peak reverse voltage		_	250	V
V _{RRM}	repetitive peak reverse voltage	series connection		500	V
V _R	continuous reverse voltage		_	200	V
V _R	continuous reverse voltage	series connection	_	400	V
I _F	continuous forward current	single diode loaded; see Fig.2; note 1	_	225	mA
		double diode loaded; see Fig.2; note 1	_	125	mA
I _{FRM}	repetitive peak forward current		_	625	mA
I _{FSM}	non-repetitive peak forward current	square wave; $T_j = 25 \text{ °C prior to surge}$; see Fig.4			
		t = 1 μs	_	9	A
		t = 100 μs	_	3	A
		t = 10 ms	_	1.7	A
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

BAV23S

BAV23S

ELECTRICAL CHARACTERISTICS

 T_j = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode	Per diode				
V _F	forward voltage	see Fig.3			
		I _F = 100 mA	_	1.0	V
		I _F = 200 mA	_	1.25	V
V _F	forward voltage	series connection; see Fig.3			
		I _F = 100 mA	_	2.0	V
		I _F = 200 mA	_	2.5	V
I _R	reverse current	see Fig.5			
		V _R = 200 V	_	100	nA
		V _R = 200 V; T _j = 150 °C	_	100	μA
I _R	reverse current	series connection	_		
		V _R = 400 V	_	100	nA
		V _R = 400 V; T _j = 150 °C	_	100	μA
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	_	5	pF
t _{rr}	reverse recovery time	when switched from $I_F = 30$ mA to $I_R = 30$ mA; $R_L = 100 \Omega$; measured at $I_R = 3$ mA; see Fig.7	_	50	ns

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		360	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Device mounted on an FR4 printed-circuit board.

Product specification

BAV23S

GRAPHICAL DATA





BAV23S



Product specification

PACKAGE OUTLINE



DEFINITIONS

Objective specificationThis data sheet contains target or goal specifications for product development.Preliminary specificationThis data sheet contains preliminary data; supplementary data may be published later.Product specificationThis data sheet contains final product specifications.Limiting valuesLimiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	Data Sheet Status			
Product specification This data sheet contains final product specifications. Limiting values Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification	Objective specification	This data sheet contains target or goal specifications for product development.		
Limiting values Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification	Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification	Product specification	This data sheet contains final product specifications.		
more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification	Limiting values			

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

BAV23S